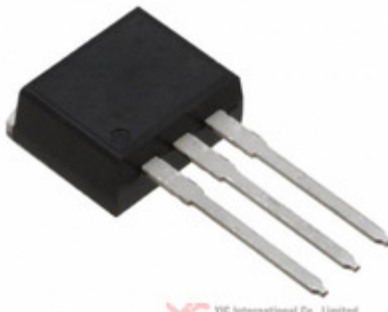



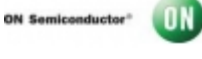





	FQI11P06TU	
	Hersteller-Teilenummer:	FQI11P06TU
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	MOSFET P-CH 60V 11.4A I2PAK
<p>Image may be representation. See specs for product details.</p>	Datenblätter:	 FQI11P06TU.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 880 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS

Spezifikationen

Teilenummer	FQI11P06TU
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET P-CH 60V 11.4A I2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	880 pcs Stock
detaillierte Beschreibung	P-Channel 60V 11.4A (Tc) 3.13W (Ta), 53W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-262-3 Long Leads, I ² Pak, TO-262AA
Supplier Device-Gehäuse	I2PAK (TO-262)
Verlustleistung (max)	3.13W (Ta), 53W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	11.4A (Tc)
Rds On (Max) @ Id, Vgs	175 mOhm @ 5.7A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	17nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	550pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)




































FQI11P06TU ist neu im Original, Suche FQI11P06TU Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQI11P06TU AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQI11P06TU: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQI12N50TU AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 12.1A I2PAK</p>	 <p>FQI11P06TU Fairchild/ON Semiconductor MOSFET P-CH 60V 11.4A I2PAK</p>	 <p>FQI11N40TU AMI Semiconductor / ON Semiconductor MOSFET N-CH 400V 11.4A I2PAK</p>	 <p>FQI11N40TU Fairchild/ON Semiconductor MOSFET N-CH 400V 11.4A I2PAK</p>
 <p>FQI12N60CTU AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 12A I2PAK</p>	 <p>FQI12N50TU Fairchild/ON Semiconductor MOSFET N-CH 500V 12.1A I2PAK</p>	 <p>FQI10N60CTU Fairchild/ON Semiconductor MOSFET N-CH 600V 9.5A I2PAK</p>	 <p>FQI12N60C FSC FQI12N60C FSC</p>

heiße Teile

Mehr

 FQI10N20CTU	 FQI10N20CTU	 FQI10N20LTU	 FQI11P06TU	 FQI12N60C
 FQI13N06	 FQI13N06L	 FQI13N50	 FQI13N50C	 FQI13N50CTU
 FQI13N50CTU	 FQI16N15TU	 FQI17N08L	 FQI17P06TU	 FQI17P06TU
 FQI17P20	 FQI19N10LTU	 FQI19N20TU	 FQI19N20TU	 FQI27N25TU
 FQI27N25TU	 FQI2N50TU	 FQI2NA90	 FQI2P25TU	 FQI2P25TU
 FQI3N25TU	 FQI3N25TU	 FQI3N30TU	 FQI3N30TU	 FQI47P06TU
 FQI47P06TU	 FQI4N20TU	 FQI4N20TU	 FQI4N80TU	 FQI4N80TU
 FQI4N90TU	 FQI4N90TU	 FQI50N06	 FQI50N06L	 FQI5N20L
 FQI5N50CTU	 FQI5N50CTU	 FQI5N50TU	 FQI5N60C	 FQI5N60CTU
 FQI5N60CTU	 FQI5N60TU	 FQI6N25TU	 FQI6N40TU	 FQI6N60C

Contact us: Info@Y-IC.com

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